TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA2002F, TA2002FN

1

Stereo Headphone Amplifier (3V USE)

The TA2002F, TA2002FN are developed for play-back stereo headphone equipments (3V use).

They are built in dual auto-reverse preamplifier, dual OCL power amplifier, and a ripple filter.

Features

Power amplifier stage

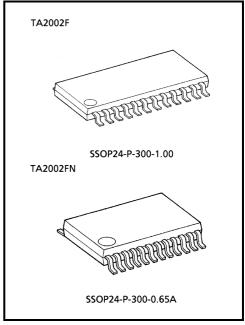
- OCL (output condenser-less)
- Low noise: $V_{no} = 22\mu V_{rms}$ (typ.)
- Excellent ripple rejection ratio: RR = 62dB (typ.)
- Voltage gain: GV = 27dB (typ.)
- Built-in a power amplifier mute
- Built-in input capacitor for reducing buzz noise

Preamplifier stage

- Auto-reverse with F / R control switch
- Input coupling condenser—less
- Low noise: $V_{ni} = 1.3 \mu V_{rms}$ (typ.)
- Built-in a preamplifier mute
- Built-in input capacitor for reducing buzz noise

Total

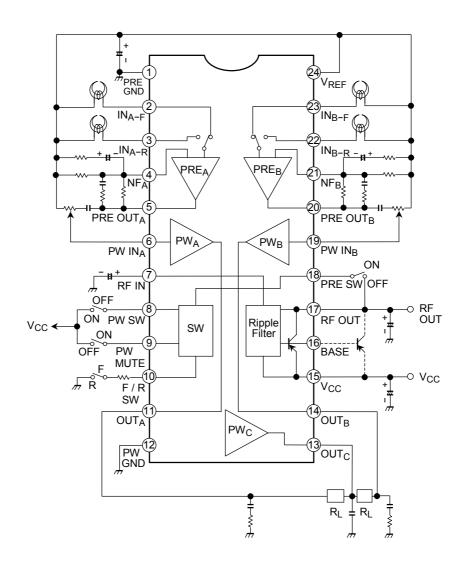
- Built-in a ripple filter
- Built-in a power switch
- Low quiescent current : ICCQ = 11.5mA (typ.) (VCC = 3V, Ta = 25°C)
- Operating supply voltage range: V_{CC} (opr) = 1.8~4.5V (Ta = 25°C)



Weight

SSOP24-P-300-1.00 : 0.32 g (typ.) SSOP24-P-300-0.65A : 0.14 g (typ.)

Block Dirgram



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Terminal Explanation Terminal Voltage: Typical Terminal Voltage at no Signal with Test Circuit $(V_{CC} = 3V, Ta = 25^{\circ}C)$

	Terminal	Function	Internal Circuit	Terminal	
No.	Name	T different	mental official	Voltage (V)	
1	PRE GND	The GND, except the power drive stage.			
2	IN _{A-F}		17.		
3	IN _{A-R}	Input of preamplifier. F / R SW	Ÿ ♦ ♦	1.3	
22	IN _{B-R}	OPEN: (2) / (23) pin "L" : (3) / (22) pin	3	1.0	
23	IN _{B-F}		V _{REF} (101)		
4	NFA	─ NF of preamplifier.	2 50017	1.3	
21	NFB		<i>#</i>		
5	PRE OUT _A	Output of preamplifier.		1.3	
20	PRE OUT _B				
6	PW INA	— Input of power amplifier.	CYNOX VREF	1.3	
19	PW IN _B		6 500Ω (I) 10 10 10 10 10 10 10 10 10 10 10 10 10		
11	OUTA	— Output of power amplifier.	22kΩ #/	1.3	
14	OUTB		1kΩ W→ V _{REF}		
7	RF IN	Ripple filter terminal.	232g 100kΩ 7 # 100kΩ	2.6	
8	PW SW	Power on / off switch. VCC: Power on OPEN or GND: Power off	Λcc — 8 — 20χΩ — 10χΩ	_	
9	PW MUTE	Muting switch for power amplifier. V _{CC} : Power amp. on OPEN or GND: Power amp. off	Vcc - 9 20kΩ - W - W - W - W - W - W - W - W - W -	_	

Terminal		Function	Internal Circuit	Terminal Voltage	
No.	Name	T directori	internal energy	(V)	
10	F/RSW	Forward / reverse mode switch. OPEN: Forward mode "L" level: Reverse mode ** This terminal can't be connected with GND line directly. In case of reverse mode, a resistor (R = 180kΩ~270kΩ) should be connected to GND.			
12	PW GND	GND for power drive stage.	_	0	
13	OUT _C	Output terminal of center power amplifier.			
15	V _{CC}	_	_	3	
16	BASE	Base bias of an external PNP transistor for ripple filer.	RF OUT O + + + + + + + + + + + + + + + + + +	2.3	
17	RF OUT	Ripple filter output. Ripple filter circuit supplies internal circuit except power amplifier circuit with power source.		2.6	
18	PRE SW	Muting switch for preamplifier. $V_{17}(RF\ OUT): Preamp.\ off \\ OPEN: Preamp.\ on \\ \underbrace{This\ terminal\ can't\ be\ connected}_{with\ GND\ line\ directly.}$ In case that terminal is connected with GND line, a resistor $(R \ge 10 k\Omega)$ should be connected to GND.	100kΩ to F / R SW	_	
24	V _{REF}	Reference voltage. Preamplifier and power amplifier operate on this reference.	16.5kg 13kg	1.3	

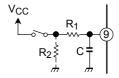
Application Note

(1) PW SW

It is necessary to connect an external pull-down resistor with the terminal PW SW (pin (8)), in case that this IC is turned on due to external noise etc.

(2) PW MUTE

The leak current flows through the terminal of PW MUTE (pin(9)), in case that the terminal is connected with VCC line independently, even though this IC is off–mode (the terminal of PW SW (pin(8)) is off–mode). It is advised to connect R_1 and C with the terminal of PW MUTE, to reduce a pop sound in switchover between PW mute on / off. And it is advised to connect R_2 , to shorten a switchover time from PW MUTE off–mode to PW MUTE on–mode (see Fig.1). It is better that the constants are $R_1 = R_2 = 100 k\Omega$, $C = 1 \mu F$ at VCC = 3V.



As for the constants, select the optimum one depending on each a set carefully.

Fig.1 PW mute circuit reducing a pop sound

(3) F / R SW

The terminal of F / R SW (pin(10)) should not be applied to higher voltage than V_{17} (RF OUT), because the ripple filter circuit supplies the F / R SW circuit with power source. And in reverse mode, the terminal of F / R SW should be connected with GND line through R_3 ($180{\sim}270k\Omega$), because the F / R SW circuit doesn't operate normally. It is advised to connect an external capacitor ($C_3 = 1\mu F$), in order to reduce a pop sound in switchover between F / R mode (see Fig.2). As for the constants, select the optimum one depending on each a set carefully.

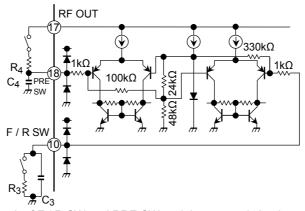


Fig.2 Internal equivalent circuit of F / R SW and PRE SW and the external circuits reducing a pop sound in switchover.

In controlling the F / R SW with voltage source, it is applied as follows;

Forward mode: 0.8V~V₁₇ (RF OUT) Reverse mode: 0.15V~0.35V

(4) PRE SW

The terminal of PRE SW (pin(18)) should not be applied to higher voltage than V_{17} (RF out), because ripple filter circuit supplies the PRE SW circuit with power source. And this terminal can't be connected with GND line directly, because the PRE SW circuit doesn't operate normally.

In case of preamplifier on–mode, this terminal should be opened or connected with GND line through a resister $(R \ge 10 k\Omega)$.

It is advised to connect a external resistor $(R_4 = 100 \sim 330 k\Omega)$ and capacitor $(C_4 = 1\mu F)$, in order to reduce a pop sound in switchover between PRE SW on / off mode (see Fig.2). As for the constants, select the optimum one depending on each a set carefully.

In controlling the PRE SW with voltage source, it is applied as follows;

Preamplifier on-mode: 0.1~0.5V

Preamplifier off-mode: 1.0V~ V₁₇ (RF OUT)

(5) NF resistor of preamplifier

The NF resistor (R = $39k\Omega$; see the test circuit) should be connected, to reduce a pop sound.

(6) Input of power amplifier

In case that the volume of power amplifier is less than $10k\Omega$, it can be connected with power amplifier directly as Fig.3–1. In case more than $10k\Omega$, it is necessary to insert the coupling capacitor between volume and PW IN terminal as Fig.3–2. In case that DC current or DC voltage is applied to the terminal of PW IN, the internal circuit has unbalance and the power amplifier doesn't operate normally.

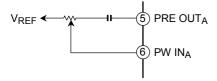


Fig.3–1 Volume connection (1) $(R \le 10k\Omega)$

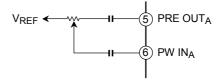


Fig.3–2 Volume connection (2) $(R > 10k\Omega)$

(7) Increase of ripple filter current

It is built in PNP transistor for a ripple filter, the current capacity is about 10mA.

Then this IC can be increased the current capacity of the ripple filter with an external transistor QX (exp. 2SA1362). In this case, as the current gain is up, it is necessary to connect external parts for phase–compensation (see Fig.4). And it is necessary to stabilize the ripple filter circuit carefully, because the ripple filter circuit supplies internal circuit except power amplifier circuit with power source.

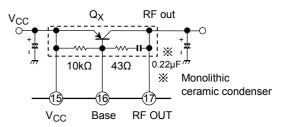


Fig.4 Increase of ripple filter current

(8) Pattern layout

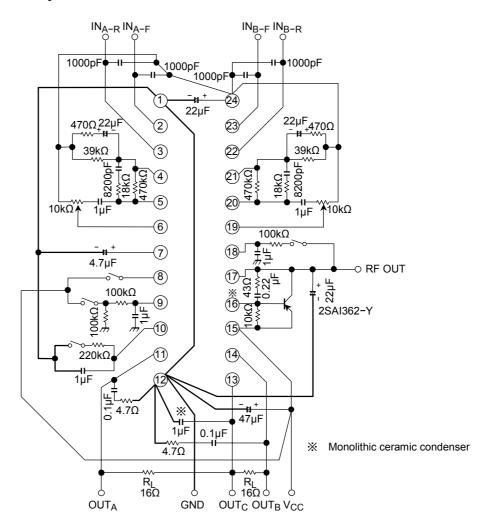
- (a) The GND line of pin(1) (PRE GND) should be isolated from that of pin(12) (PW GND) at the GND point, where the V_{CC} decoupling condenser is placed.
- (b) The GND line of capacitor (for ripple filter) should be isolated from that of compensation capacitor, at the point of pin(12) (PW GND).
- (c) The pattern diagram between the pin(24) (VREF) and capacitor should be made shortly. As for pin(1) (PRE GND), it's as well.
- (d) The pattern diagram between the pin(12) (PW GND) and compensation capacitor, should be shortly. And this positive line of compensation capacitor should be kept away from the terminals of PW IN, pin(6), (19).
- (e) The lines of PW IN should be kept away from those of PW OUT. And each of the PW OUT lines should be kept away.
- *See the example of pattern layout as shown next page.

(9) Oscillation precaution

Small temperature coefficient and excellent frequency characteristic is needed by capacitors below.

- · Oscillation preventing capacitors for power amplifier output.
- · Bypass capacitor for ripple filter
- Capacitor between VCC and GND
- Capacitor between VREF and GND

An Example Of Pattern Layout



Maximum Ratings (Ta = 25°C)

Char	acteristic	Symbol	Rating	Unit	
Supply voltage		V _{CC}	6	V	
Output current	Power	I _{o (peak)}	60	mA	
Output current	Ripple filter	I _{RF}	I _{RF} 30		
Power	TA2002F	P _D (Note)	400	mW	
dissipation	TA2002FN	FD (Note)	500		
Operating temperature		T _{opr}	-25~75	°C	
Storage temperat	ure	T _{stg}	−55~150	C	

(Note) Derated above Ta = 25° C in the proportion of 3.2mW / °C for TA2002F, and of 4mW / °C for TA2002FN.

Electrical Characteristics

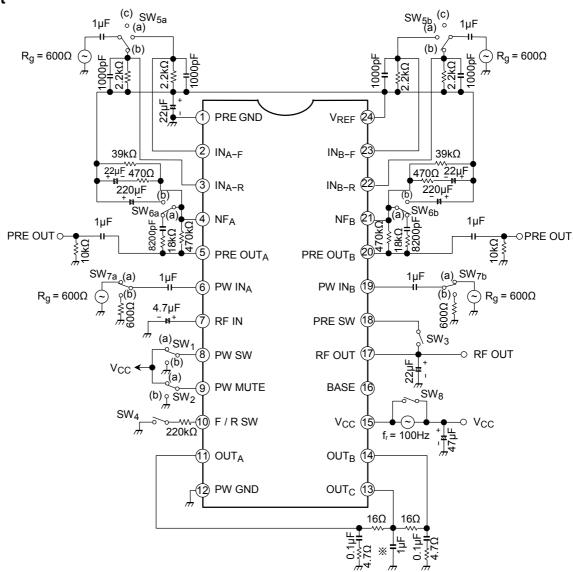
Unless Otherwise Specified: V_{CC} = 3V, f = 1kHz, Ta = 25°C, SW₁: a, SW₂: a, SW₃: OPEN, SW₈: ON

Preamplifier Stage: R_g = 2.2k Ω , R_L = 10k Ω , SW₂: OPEN, SW₄: ON / OPEN, SW₅: a / b, SW₆: a

Power Amplifier Stage: $R_q = 600\Omega$, $R_L = 16k\Omega$, SW_3 : ON, SW_7 : a

Characteristic		Sym- bol	Test Cir- cuit	Test Condition		Min.	Тур.	Max.	Unit	
Quiescent current		I _{CCQ1}		Power off, SW ₁ : b, SW ₂ : b SW ₃ : ON Power amp. off, SW ₂ : b V _{in} = 0		_	_	5	μA	
		I _{CCQ2}	<u> </u>			_	5	9	- mA	
		I _{CCQ3}				_	11.5	16.5		
υ	Voltage gain		G _V		V _O = -12dBV		25	27	29	- dB
	Channel balance		СВ				_	0	1.5	
	Output power		P _{O1}		THD = 10%	R _L = 16Ω	35	50	_	mW
stag			P _{O2}			R _L = 32Ω	_	33	_	IIIVV
lifier	Total harmonic distortion		THD1		P _O = 1mW		_	0.2	0.8	%
amp	Output noise voltage		V _{no}	_	Rg = 600Ω, SW ₇ : b		_	22	40	μV_{rms}
Power amplifier stage	Ripple rejection ratio		RR ₁		$f_r = 100Hz$, $V_r = -22dBV$ SW ₈ : OPEN		45	62	_	
	Cross talk	Cross talk (CH-A / CH-B)			V _O = -12dBV		35	42	_	dB
	Power muting attenuation		ATT1		V _O = −12dBV, SW ₂ : a→b		_	80	_	
	Open loop voltage gain		G _{VO}		$V_O = -12 dBV, SW_6$: b		70	80	_	dB
	Closed loop voltage gain		G _{VC}		V _O = -12dBV		_	35	_	
40	Maximum output voltage		V _{om}		THD = 1%		600	850	_	mV _{rms}
stage	Total harr	Total harmonic distortion			$V_O = -12dBV$		_	0.02	0.1	%
Preamplifier stage	Equivalent input noise voltage		V _{ni}	_	R_g = 2.2k Ω , BPF = 20Hz~20kHz SW ₅ : c NAB (G _V = 35dB, f = 1kHz)		_	1.3	2.8	μV _{rms}
Pre	Cross talk	Cross talk (CH-A / CH-B)			V _O = -12dBV		_	70	_	dB
	Cross talk (forward / reverse)		CT ₃				_	70	_	
	Pre muting attenuation		ATT2	V _O = −12dBV, SW ₃ : OPEN→ON		_	80	_		
Ripple	filter outp	ut voltage	V_{RF}		V _{CC} = 2V, I _{RF} = 0mA		1.76	1.8	_	٧
Ripple rejection ratio of ripple filter output		RR ₂	_	V_{CC} = 2V, I_{RF} = 10mA f_r = 100Hz, V_r = -22dBV SW ₈ : OPEN		45	53	_	dB	
Power on / off switch		Power on current	I ₈		V _{CC} = 1.8V, V ₂₄ ≥ 0.5V		5	_	_	μΑ
		Power off voltage	V ₈	_	V _{CC} = 1.8V, V ₂₄ ≤ 0.3V		0	_	0.3	٧
Power amp. mute switch		Mute off current	lg		V _{CC} = 1.8V, ATT1 ≥ 3dB		5	_	_	μΑ
		Mute on voltage	V ₉		V _{CC} = 1.8V, ATT1 ≥ 60dB		0	_	0.3	V

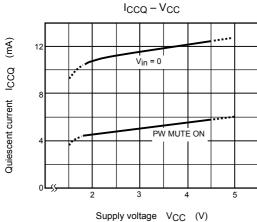
Test Circuit

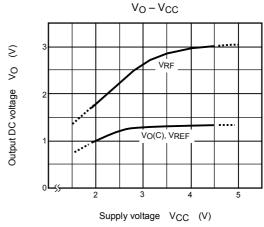


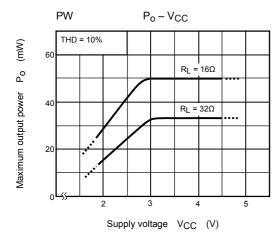
Monolithic ceramic condenser

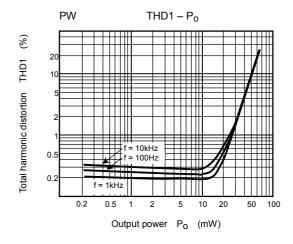
Characteristics Curves

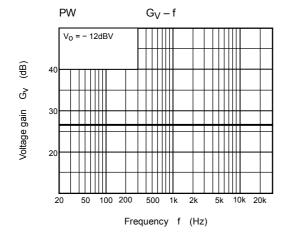
Unless Otherwise Specified: V_{CC} = 3V, f = 1kHz, Ta = 25°C Power amplifier Stage: R_g = 600 Ω , R_L = 16 Ω Preamplifier Stage: R_g = 2.2k Ω , R_L = 10k Ω

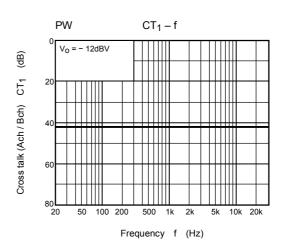


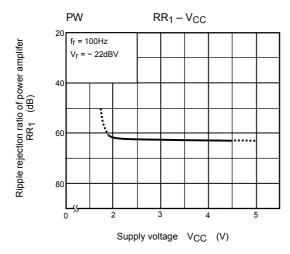


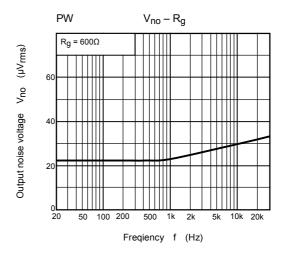


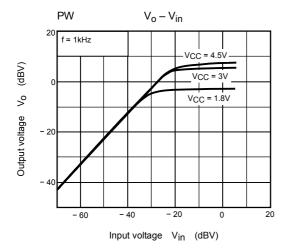


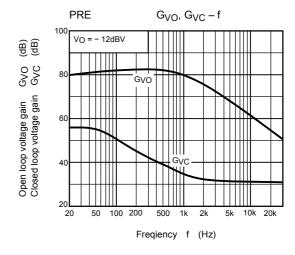


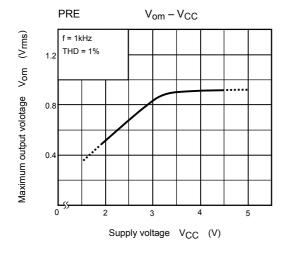


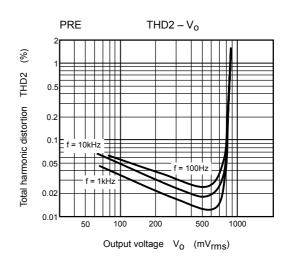


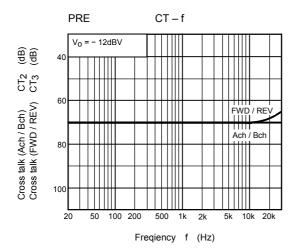


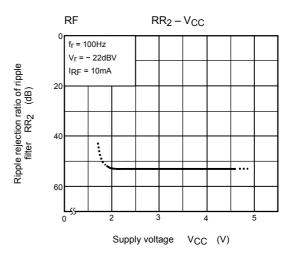


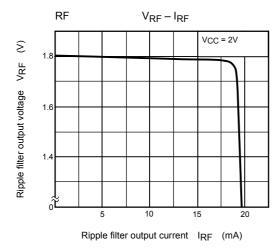


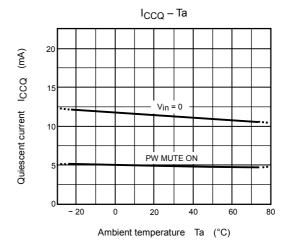


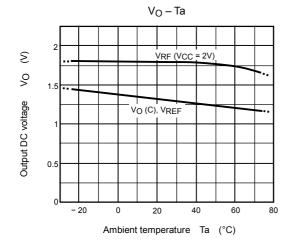


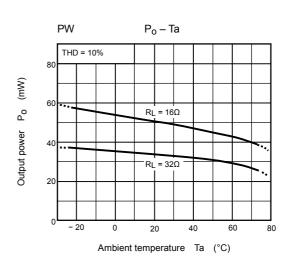


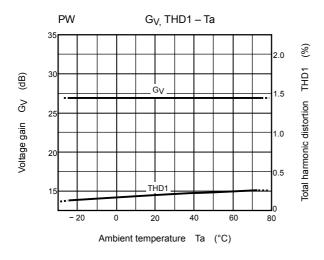


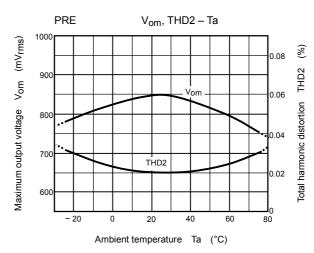


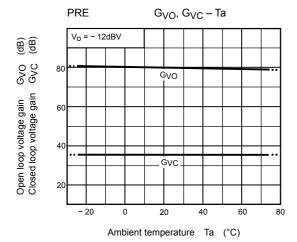


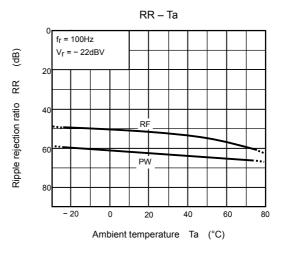


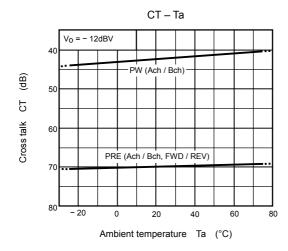




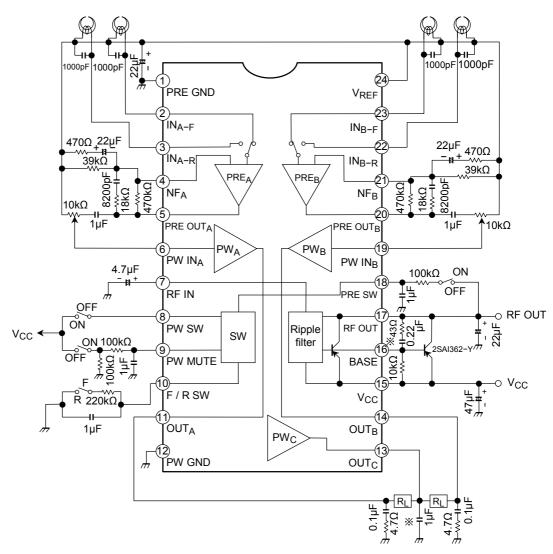








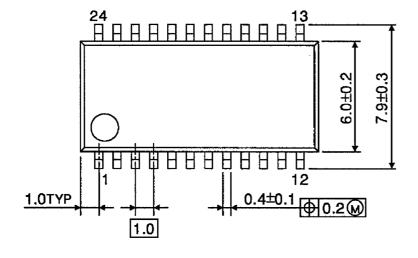
Application Circuit

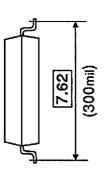


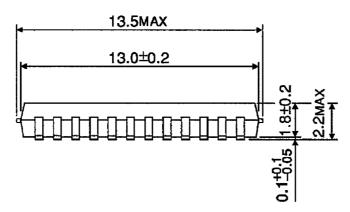
Monolithic ceramic condenser

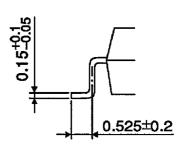
Package Dimensions

SSOP24-P-300-1.00 Unit: mm

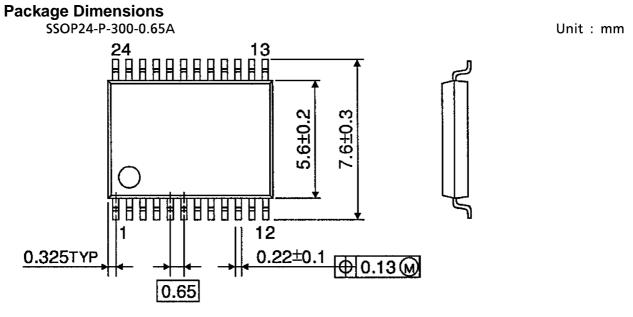


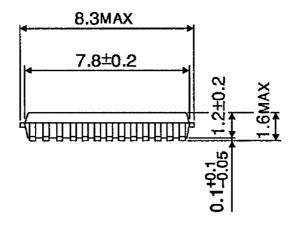


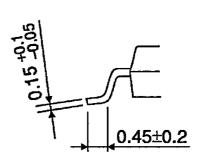




Weight: 0.32g (typ.)







Weight: 0.14g (typ.)

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